## NSN 5961-01-581-5270

Diode Semiconductor Device - Page 1 of 1



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## **Special Features:**

Shelf Life:

A110a0

20 mj avalanche energy guaranteed; ultrafast 75 nanosecond recovery time; 175 degree celsius operating junction temperature; to-220
package; epoxy meets ul94 v-0 at 0.125 inches; low forward voltage; low leakage current; high temperature glass passivated junction;
reverse voltage to 1000 v

N/a
Unit Of Measure:
Demilitarization:
No
Fiig: